First Announcemen

NODIN 2010 In Dielectrics in Microelectronics

16th Workshop June 28 – 30, 2010 in Bratislava, Slovakia

Scope

New challenges offered by the application of dielectric materials in microelectronics will be discussed during the 16th Workshop on Dielectric Materials, WoDiM 2010. The goal of the WoDiM 2010 conference is to create a stimulating international platform for application-oriented scientists to exchange ideas and the latest experimental results covering the physics, technology and characterisation of dielectric materials in silicon integrated circuits.

Topics

Emerging dielectric materials, technologies and new device approaches

Theory of dielectric materials, interface science of dielectrics in contact with semiconductors & metals Advanced technologies for thin dielectric film growth (ALD, MOCVD, PLD, MBE,...) Characterisation of dielectrics with high sensitivity & spatial resolution, characterisation at nano-scale Multiferroics, 2-DEG at dielectric interfaces, emerging dielectric materials Novel oxide-based approaches to engineer SOI and GOI wafers

Dielectrics for aggressively scaled CMOS and other field effect devices High-k dielectrics on Si

High-k dielectrics on high mobility semiconductors: Ge, III-V, III-N High-k/metal gate stack, characterisation, scaling, stability Defect characterisation, engineering of dielectrics, leakage currents Electrical characterisation and reliability of devices with alternative dielectrics

Dielectrics for memory applications

High-k dielectrics for MIM (DRAM etc.) **Resistive switching in dielectrics** Dielectrics for non-volatile memories (flash, nanocrystal-based memories,...) **Ferroelectrics**

Invited speakers

Bibes, M., CNRS/Thales and University Paris-Sud, Orsay, France Dimoulas, A., Institute of Materials Science, NCSR Demokritos, Athens, Greece Frank, M. M., IBM, Yorktown Heights, New York, USA Hashizume, T., Hokkaido University, Sapporo, Japan Kaczer, B., IMEC, Leuven, Belgium Kummel, A. C., University of California, San Diego, La Jolla, California, USA Lucovsky, G., NC State University, Raleigh, North Carolina, USA Paskaleva, A., ISSP, Sofia, Bulgaria, Ritala, M., University of Helsinky, Helsinky, Finland Schlom, D. G., Cornell University, Ithaca, New York, USA Waser, R., RWTH Aachen, Aachen, Germany Wenger, Ch., IHP, Frankfurt (Oder), Germany, Zubko, P., University of Geneva, Geneva, Switzerland

WDIM 2010 will be organized by the Institute of Electrical Engineering, SAS, Bratislava http://www.wodim2010.sk/ For further informations, please consult our web page: